



# DATA SHEET

SEMICONDUCTOR

2SA1037AKx Series

## General Purpose Transistors

PNP Silicon



### Features

- We declare that the material of product compliance with RoHS requirements.

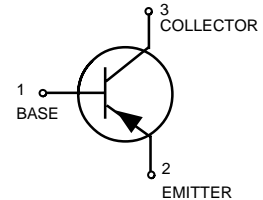
### ORDERING INFORMATION

Device	Package	Shipping
2SA1037AKX	SOT23	3000/Tape & Reel

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	-50	V
Collector-Base Voltage	$V_{CBO}$	-60	V
Emitter-Base Voltage	$V_{EBO}$	-6.0	V
Collector Current — Continuous	$I_C$	-150	mAdc
Collector power dissipation	$P_C$	0.2	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 ~ +150	°C

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### DEVICE MARKING

2SA1037AKQ=FQ 2SA1037AKS=G3F 2SA1037AKR=FR
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### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Collector-Emitter Breakdown Voltage ( $I_C = -1\text{ mA}$ )	$V_{(BR)CEO}$	- 50	—	—	V
Emitter-Base Breakdown Voltage ( $I_E = - 50\ \mu\text{A}$ )	$V_{(BR)EBO}$	- 6	—	—	V
Collector-Base Breakdown Voltage ( $I_C = - 50\ \mu\text{A}$ )	$V_{(BR)CBO}$	- 60	—	—	V
Collector Cutoff Current ( $V_{CB} = - 60\text{ V}$ )	$I_{CBO}$	—	—	- 0.1	$\mu\text{A}$
Emitter cutoff current ( $V_{EB} = - 6\text{ V}$ )	$I_{EBO}$	—	—	- 0.1	$\mu\text{A}$
Collector-emitter saturation voltage ( $I_C / I_E = - 50\text{ mA} / - 5\text{ mA}$ )	$V_{CE(sat)}$	—	—	-0.5	V
DC current transfer ratio ( $V_{CE} = - 6\text{ V}, I_C = - 1\text{ mA}$ )	$h_{FE}$	120	—	560	—
Transition frequency ( $V_{CE} = - 12\text{ V}, I_E = 2\text{ mA}, f = 30\text{ MHz}$ )	$f_T$	—	140	—	MHz
Output capacitance ( $V_{CB} = - 12\text{ V}, I_E = 0\text{ A}, f = 1\text{ MHz}$ )	$C_{ob}$	—	4.0	5.0	pF

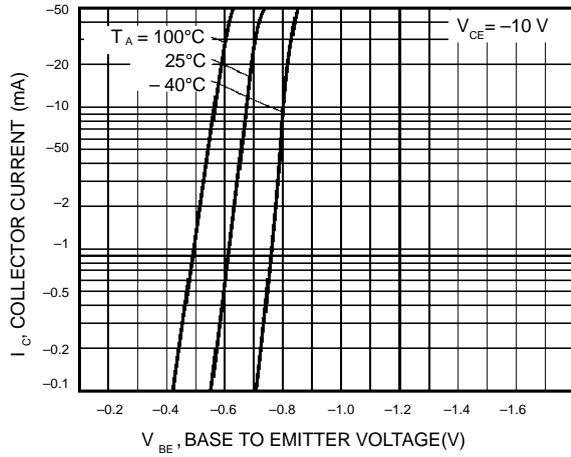
$h_{FE}$  values are classified as follows:

*	Q	R	S
$h_{FE}$	120~270	180~390	270~560

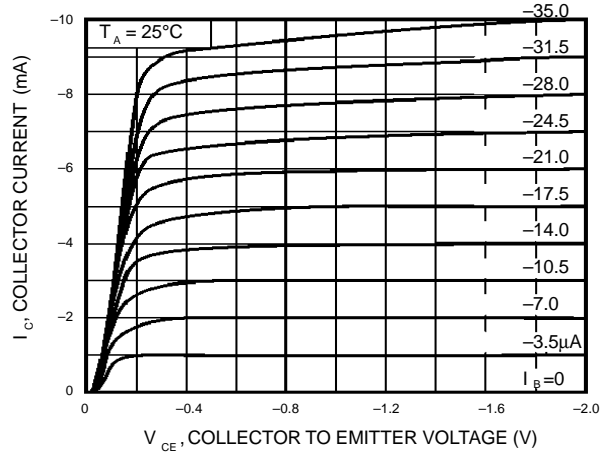
# DEVICE CHARACTERISTICS

## 2SA1037AKx Series

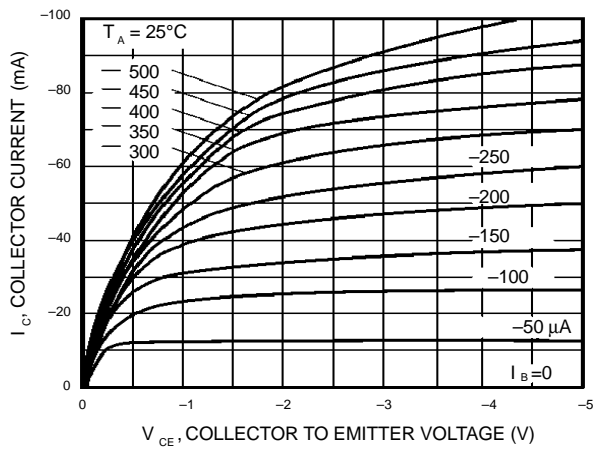
**Fig.1** Grounded emitter propagation characteristics



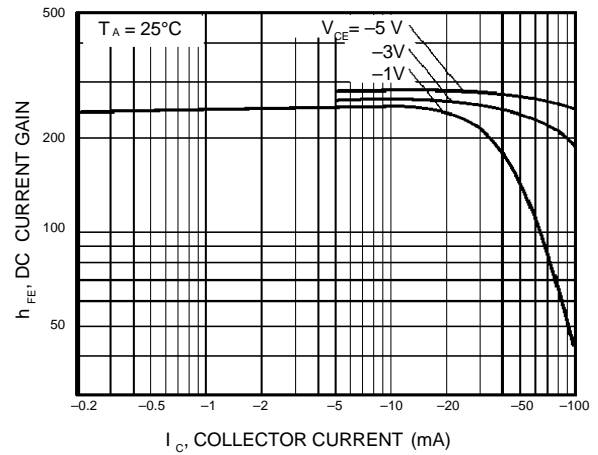
**Fig.2** Grounded emitter output characteristics(I)



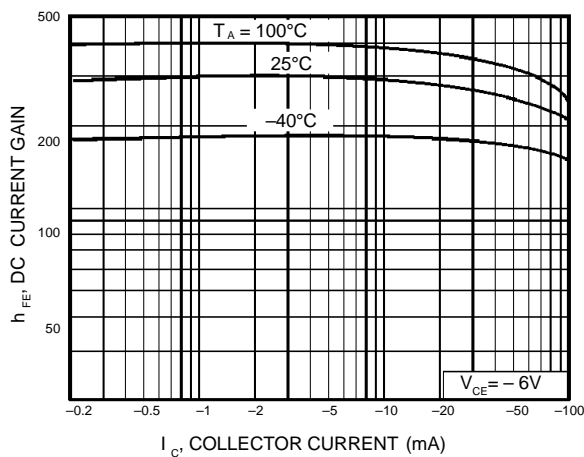
**Fig.3** Grounded emitter output characteristics(II)



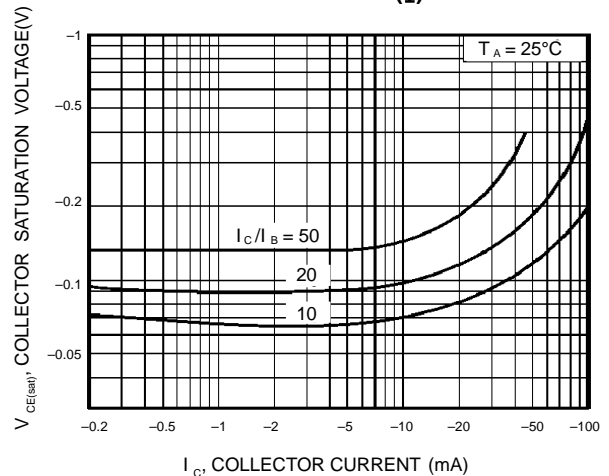
**Fig.4** DC current gain vs. collector current (I)



**Fig.5** DC current gain vs. collector current (II)



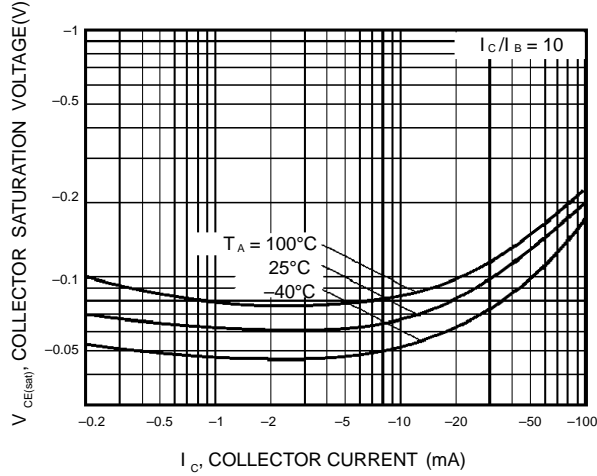
**Fig.6** Collector-emitter saturation voltage vs. collector current (I)



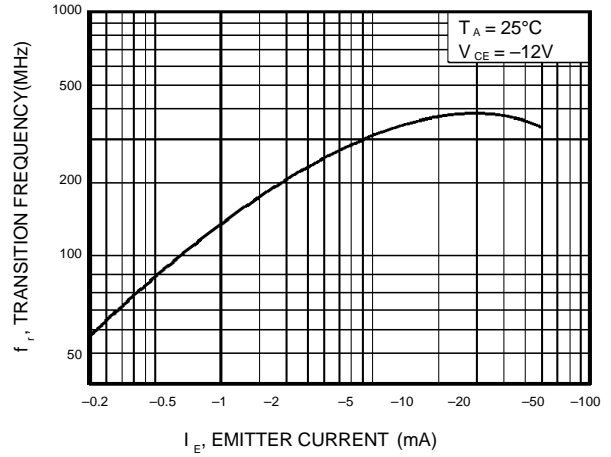
# DEVICE CHARACTERISTICS

## 2SA1037AKx Series

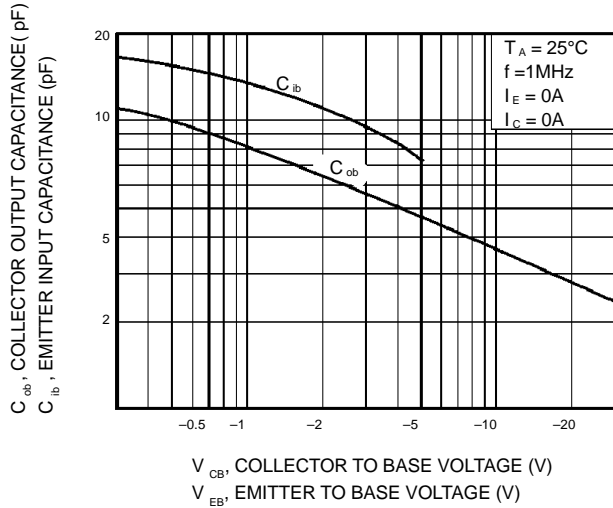
**Fig.7 Collector-emitter saturation voltage vs. collector current (II)**



**Fig.8 Gain bandwidth product vs. emitter current**



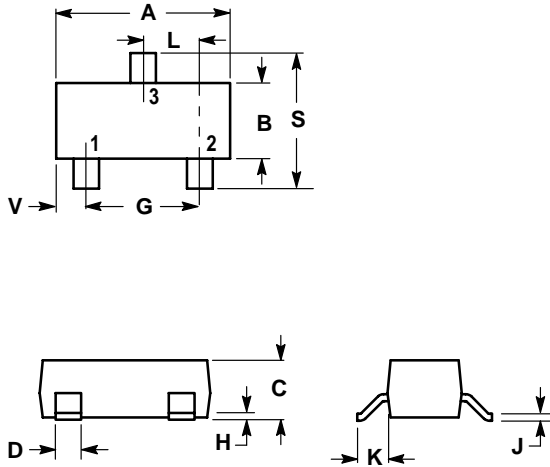
**Fig.9 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage**



# PACKAGE OUTLINE & DIMENSIONS

## 2SA1037AKx Series

### SOT-23



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

